

FIG. 1A

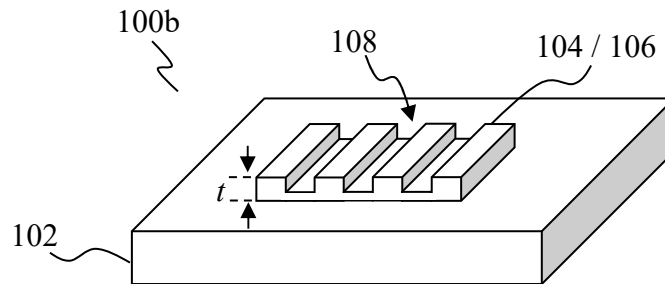


FIG. 1B

120
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Form a layer having elemental germanium on a polar crystal substrate, the polar crystal substrate being configured to support the surface phonon-polaritons in the device, and the layer being configured to confine the surface phonon-polaritons, wherein the layer has a thickness of about 50 nm or less.

FIG. 1C

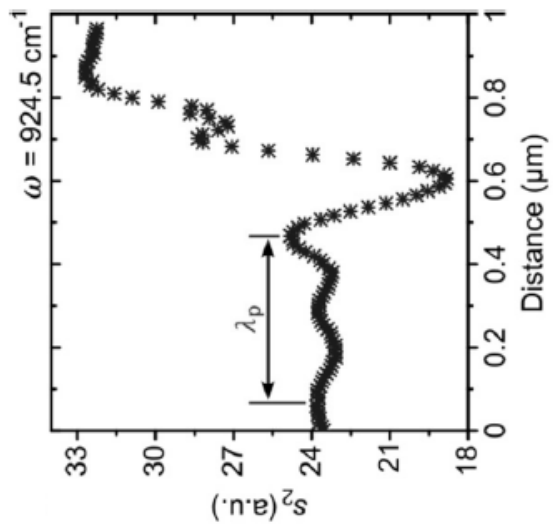


FIG. 2D

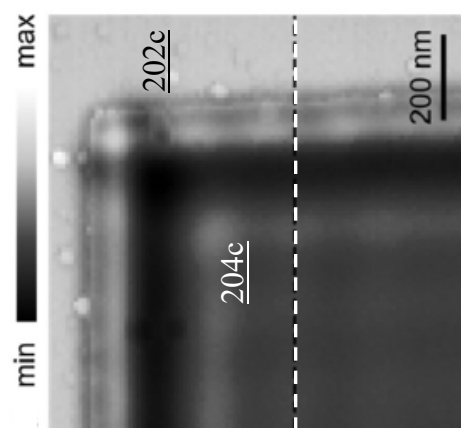


FIG. 2C

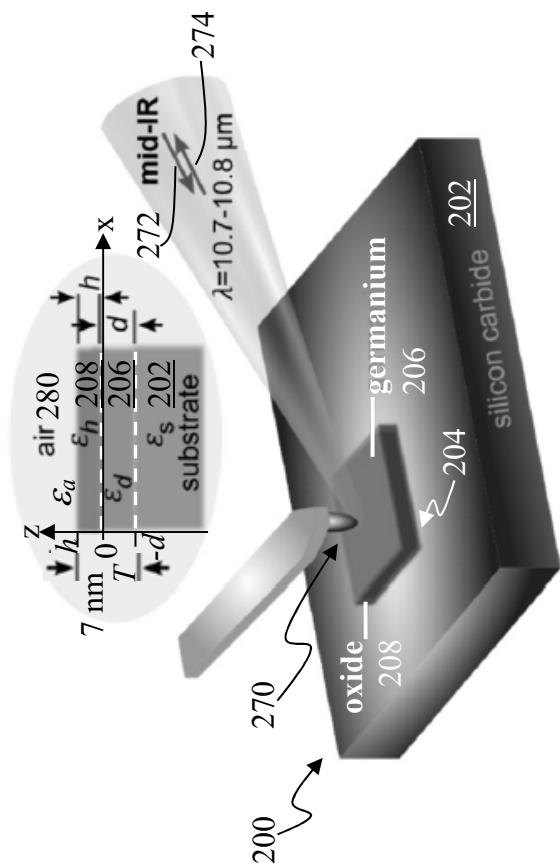


FIG. 2A

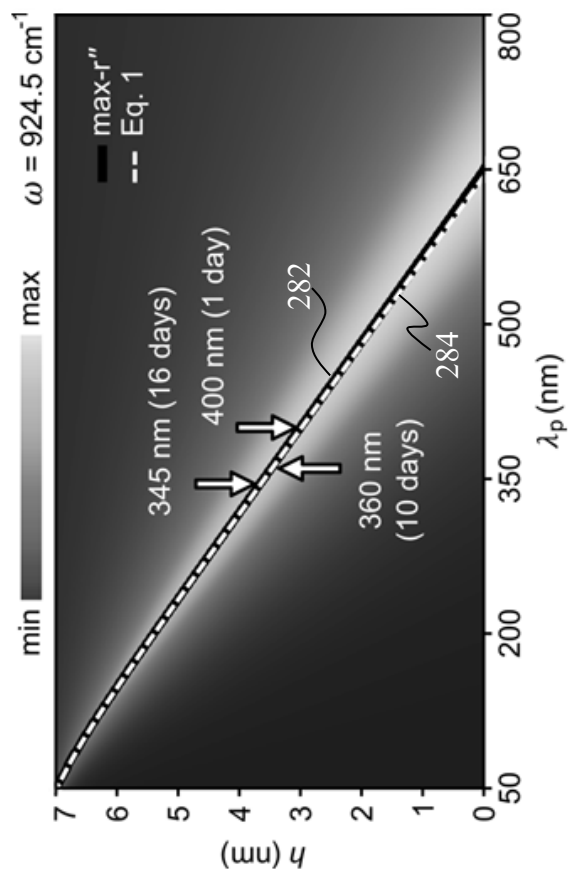


FIG. 2B

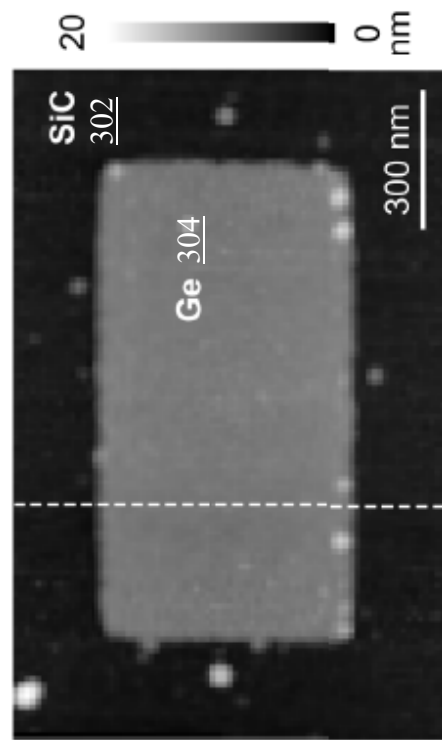


FIG. 3A

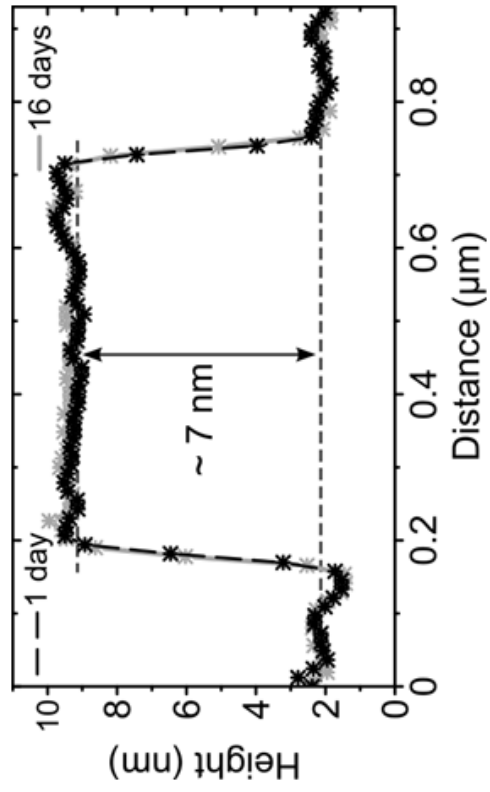


FIG. 3B

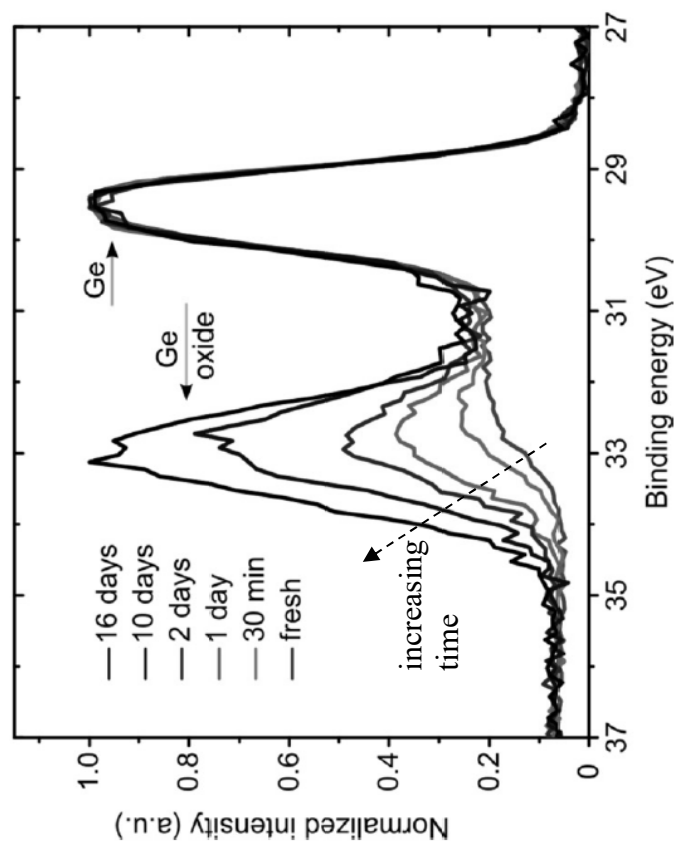


FIG. 4A

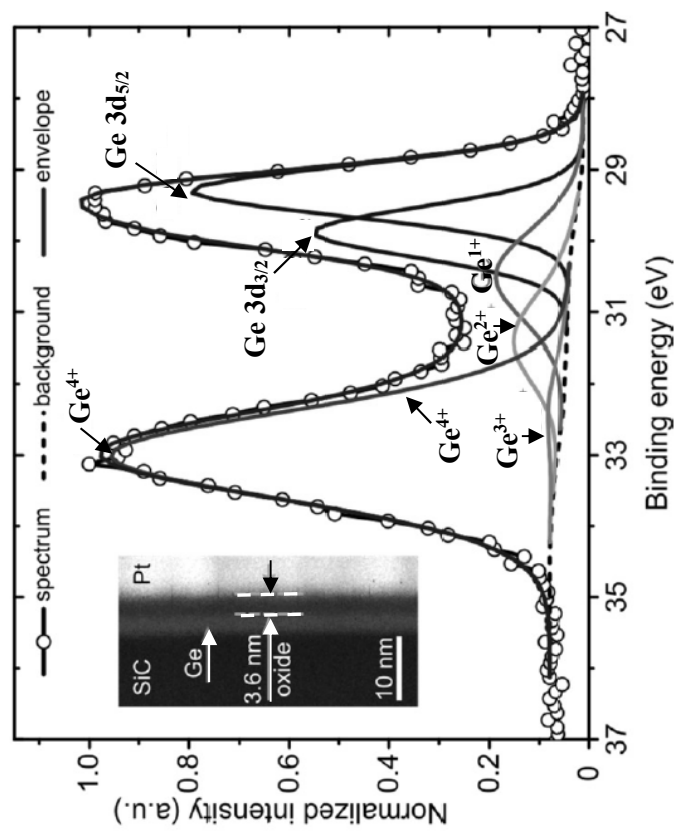


FIG. 4B

min max

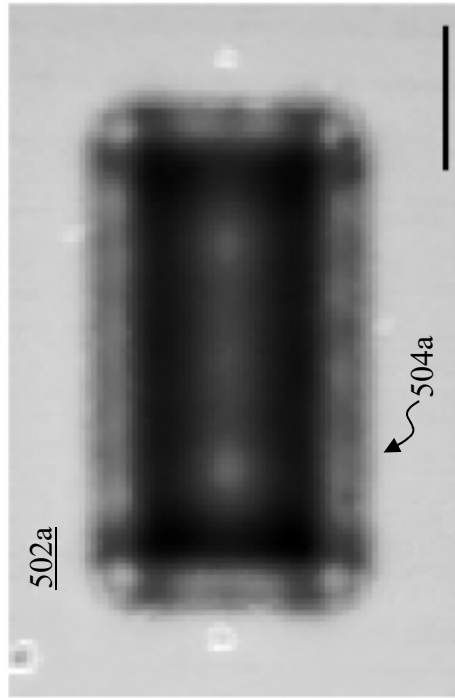


FIG. 5A

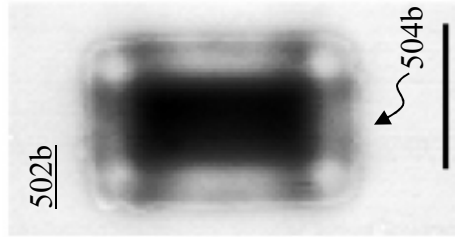


FIG. 5B

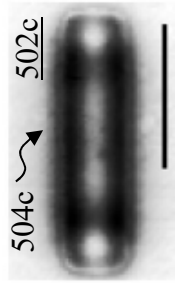


FIG. 5C



FIG. 5D

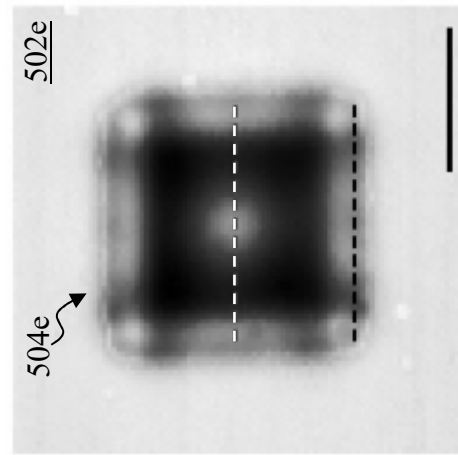


FIG. 5E

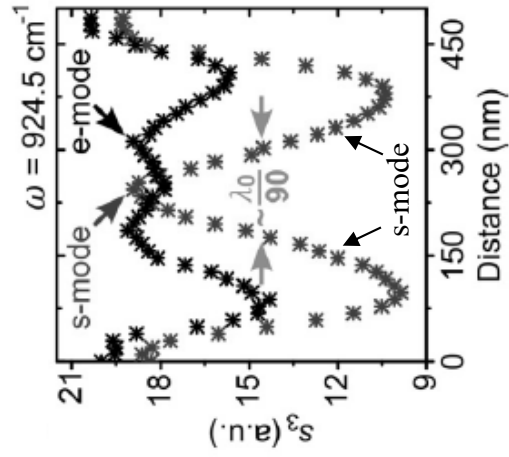


FIG. 5F

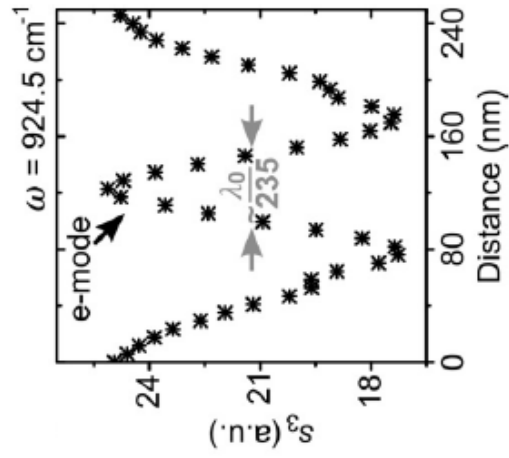


FIG. 5G

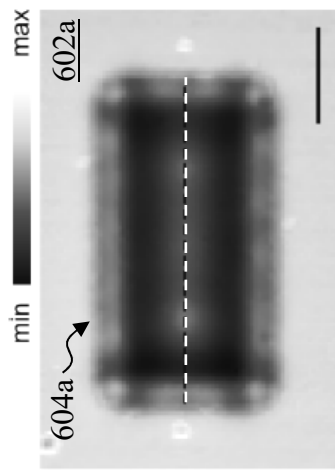


FIG. 6A

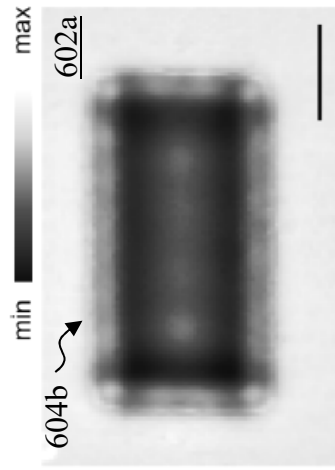


FIG. 6B

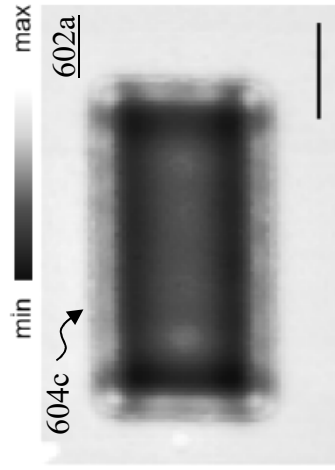


FIG. 6C

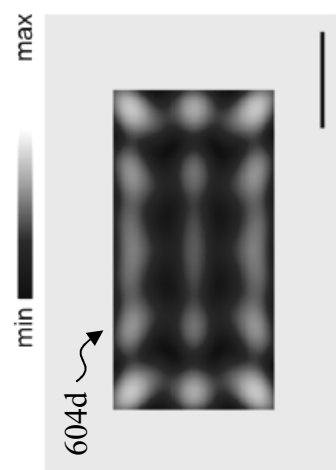


FIG. 6D

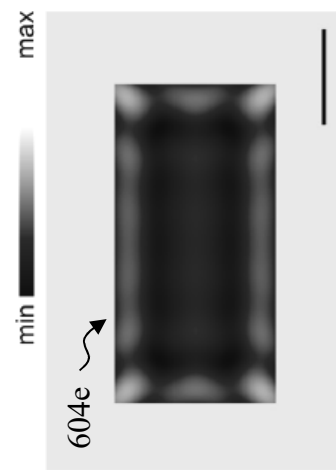


FIG. 6E

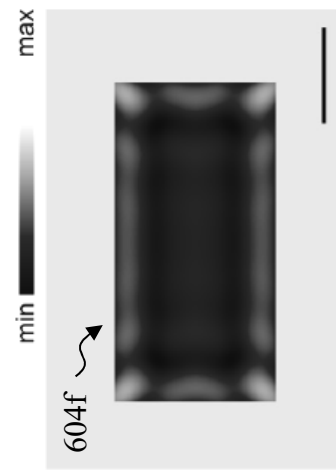


FIG. 6F

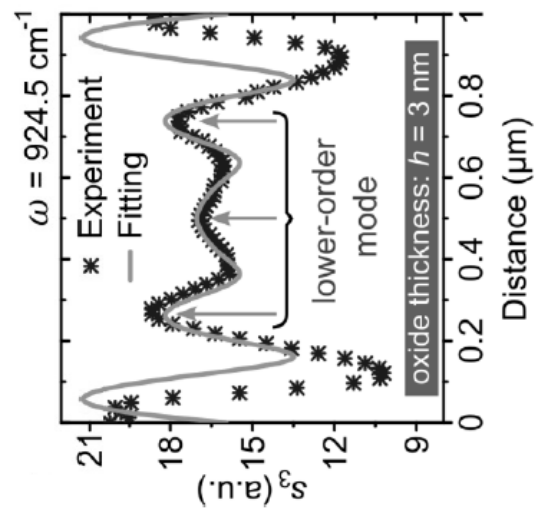


FIG. 6G

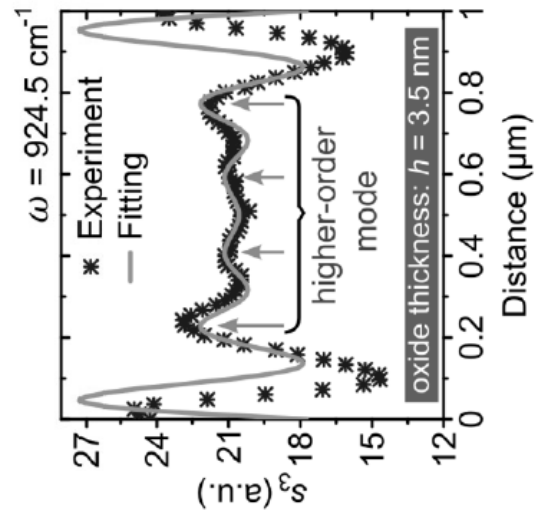


FIG. 6H

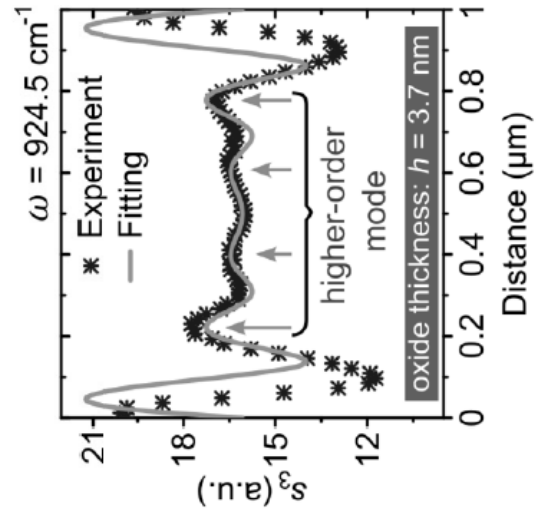


FIG. 6I

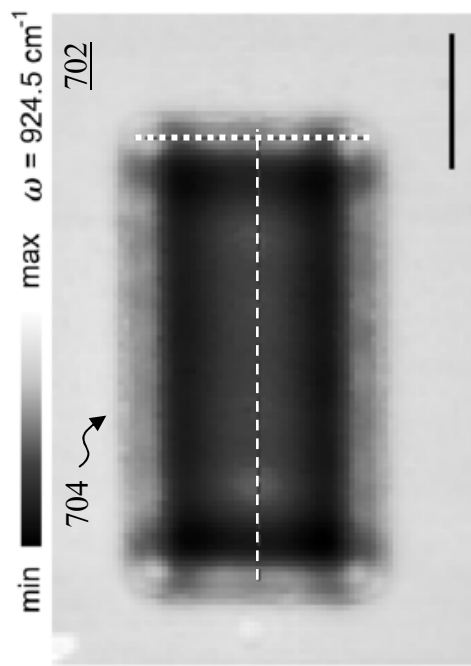


FIG. 7A

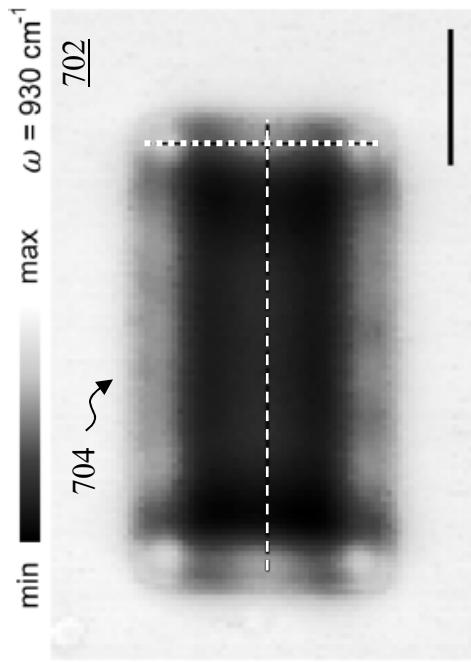


FIG. 7B

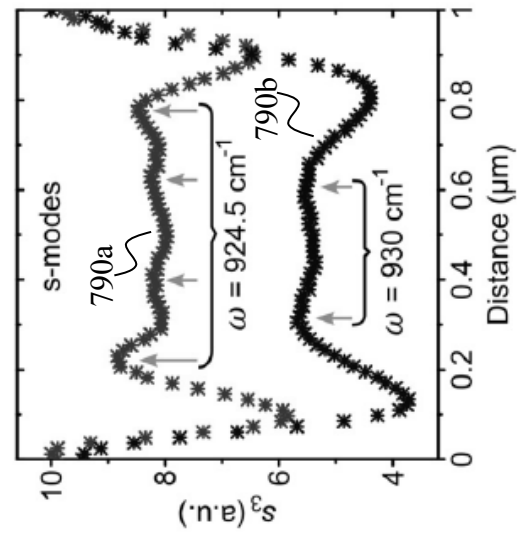


FIG. 7C

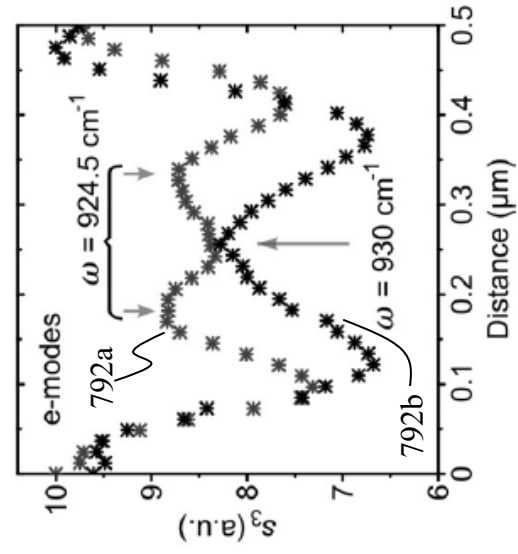


FIG. 7D

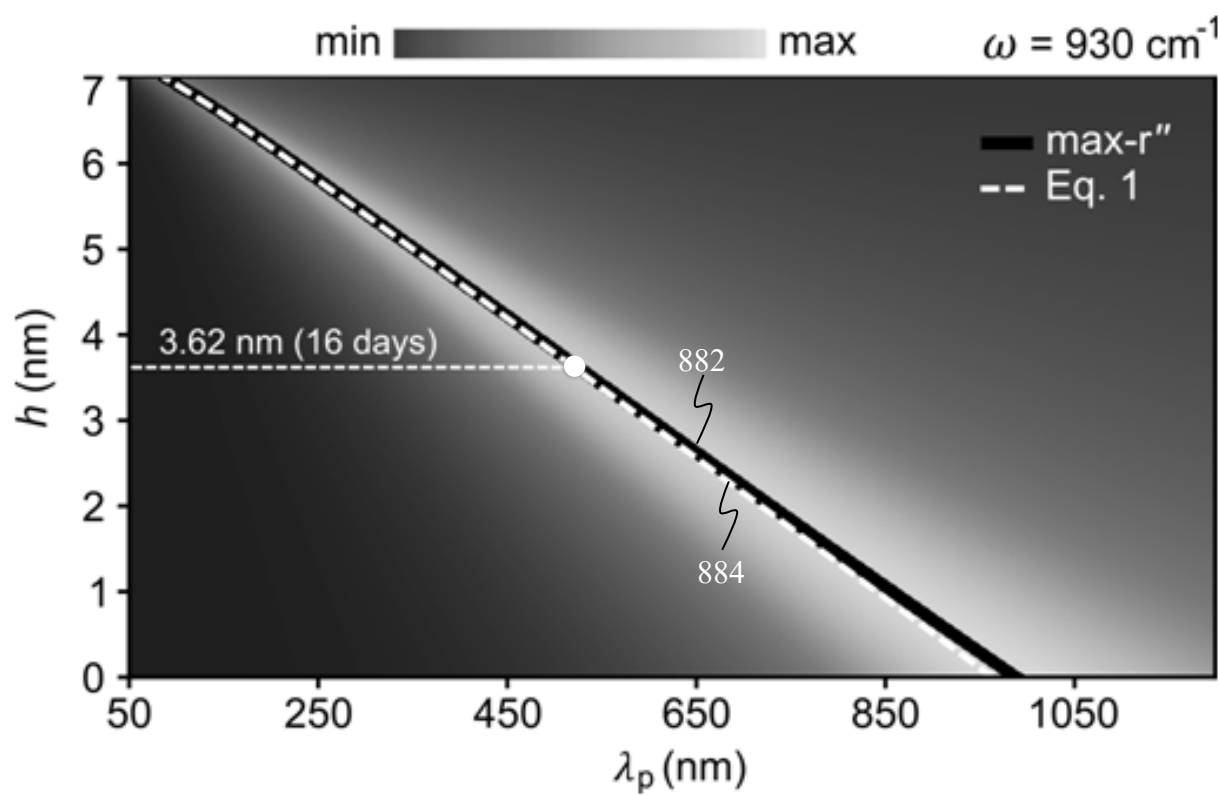


FIG. 8

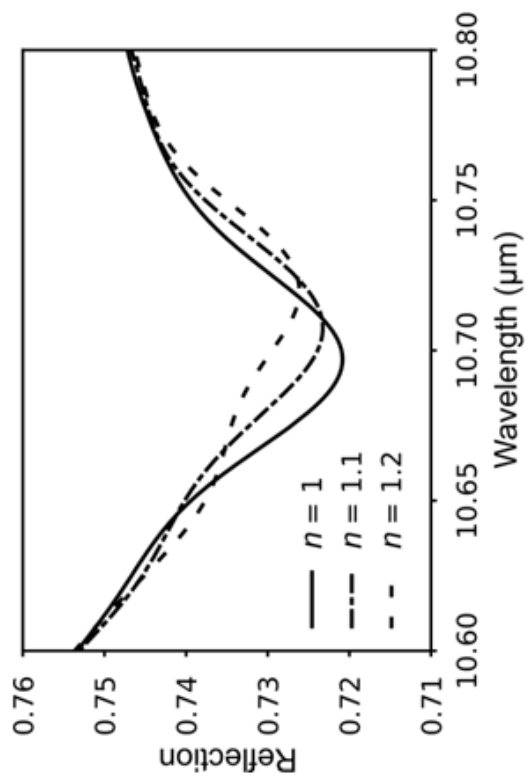


FIG. 9A

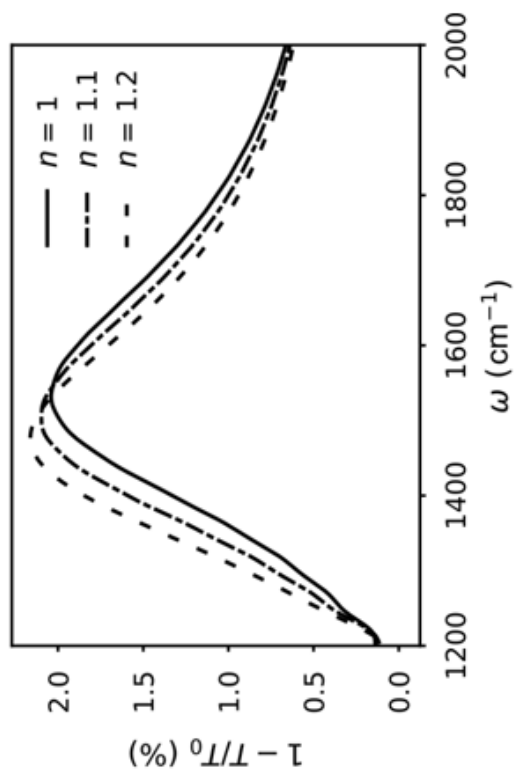


FIG. 9B

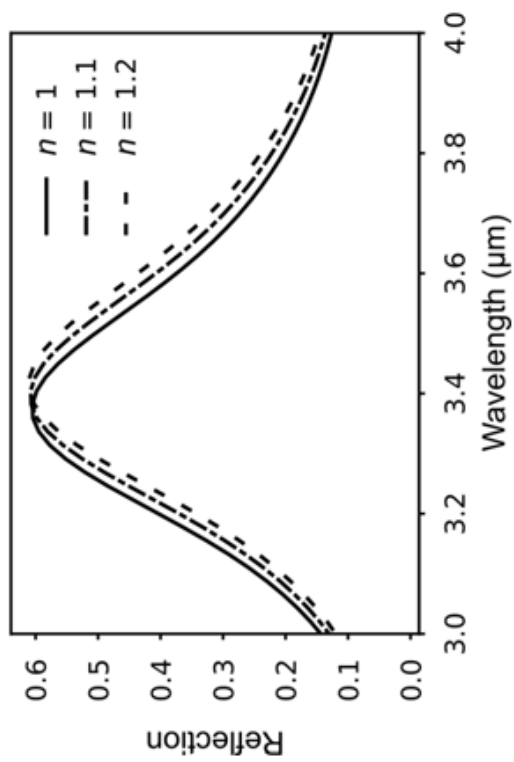


FIG. 9C

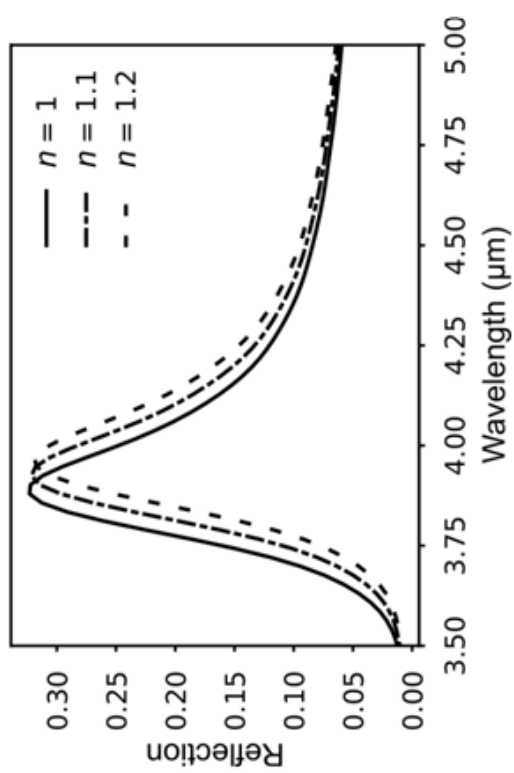


FIG. 9D